

SANYO Semiconductors DATA SHEET

SBE807—Schottky Barrier Diode 30V, 1.0A Rectifier

Applications

· High frequency rectification (switching regulators, converters, and choppers).

Features

- · Low switching noise.
- Low reverse current (V_R=16V, I_R max=15μA).

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		30	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		35	V
Average Output Current	IO		1.0	Α
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	10	А
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Electrical Characteristics at Ta=25°C

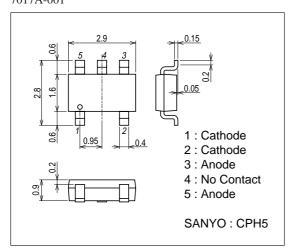
Parameter	Cumbal	Conditions	Ratings			1.114
	Symbol		min	typ	max	Unit
Reverse Voltage	VR	I _R =0.2mA	30			V
Forward Voltage	V _F 1	IF=0.7A		0.45	0.50	V
	VF2	IF=1.0A		0.48	0.53	V
Reverse Current	IR	V _R =16V			15	μΑ
Interterminal Capacitance	С	V _R =10V, f=1MHz		27		pF
Reverse Recovery Time	t _{rr}	IF=IR=100mA, See specified Test Circuit.			10	ns
Thermal Resistance	Rth(j-a)	When mounted on ceramic substrate (900mm²X0.8mm)		111		°C / W

Marking : SJ

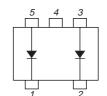
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Package Dimensions

unit : mm (typ) 7017A-001

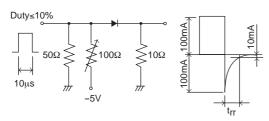


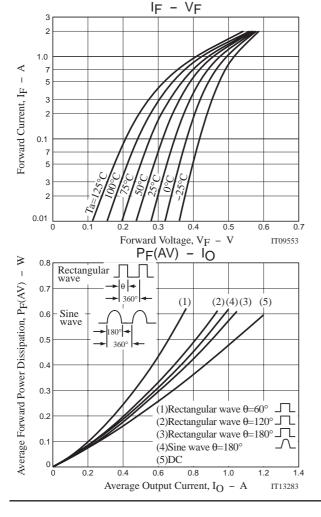
Electrical Connection

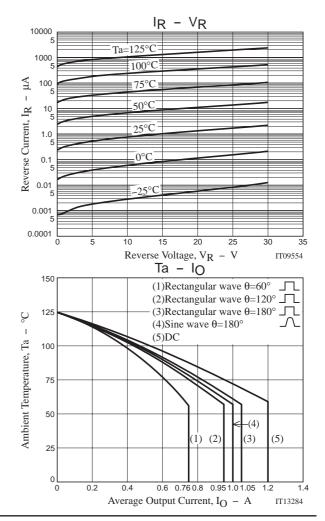


- 1 : Cathode 2 : Cathode 3 : Anode
- 4 : No Contact 5 : Anode
- Top view

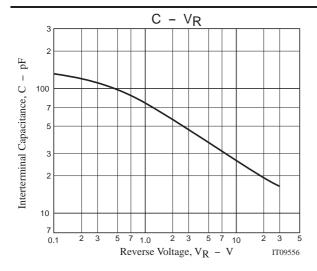
trr Test Circuit

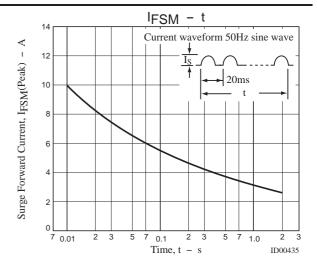






SBE807





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